



1		Icc	mA	-	-	300
			mV	150		1100
			mV	300	-	600
TX_fault /LOS	(TTL)	VOH	V	2.0	-	Vcc
		VOL	V	0	-	0.8
TX_disable	(TTL)	VOH	V	2.0	-	Vcc
		VOL	V	0	-	0.8
		Po	dBm	-9.5		-3
		λc	nm	830		860
		EX	dB	9		
(RMS)		Δλ	nm			4
2		TJ	UI			0.284
3		RIN	dB/Hz			-120
		GE				
/		Trise/Tfall	ps			260
		-	dB			1
		Poff	dBm			-45
		λc	nm	770		870
4		S	dBm			-18
		Pin	dBm	0		
			dBm			-18
				-35		

		dB	0.5		5
Note1. Note2. 1.25Gbps 7 Note3. RIN 12dB Note4. PRBS 2 ⁷ -1 1.25Gb/s EX=10dB BER<10 ⁻¹²					

RTXM191-552	SFP	1.25G	850nm FP	-9.5~ -3dBm	PIN	< -18dBm	-40~85℃	0.55km	DDM, RoHS